



30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
30V	$5.5 m\Omega$ @ $V_{GS} = 10V$	45A
	$9m\Omega @ V_{GS} = 4.5V$	30A

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Description and Applications

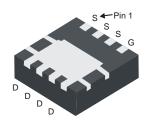
This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Power Management Functions
- DC-DC Converters
- Battery

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)

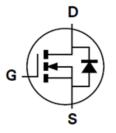
PowerDI3333-8



Bottom View



Top View



Equivalent Circuit

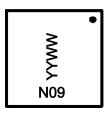
Ordering Information (Note 5)

Part Number	Case	Packaging
DMN3009SFGQ-7	PowerDI3333-8	2,000/Tape & Reel
DMN3009SFGQ-13	PowerDI3333-8	3,000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Please refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



N09 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	30	V	
Gate-Source Voltage	V_{GSS}	±20	V	
	$T_A = +25^{\circ}C$	I _D	16	A
Continuous Drain Current / 40\/ (Note 7)	$T_A = +70^{\circ}C$		13	
Continuous Drain Current, V _{GS} = 10V (Note 7)	T _C = +25°C	1	45	А
	$T_C = +70$ °C	ΙD	35	
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)	I _{DM}	80	Α	
Maximum Continuous Body Diode Forward Current (Note 7)	Is	20	Α	
Avalanche Current, L = 0.1mH	I _{AS}	33	A	
Avalanche Energy, L = 0.1mH	E _{AS}	55	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 6)	$T_A = +25$ °C	Pn	0.9	W	
Total Fower Dissipation (Note 0)	T _A = +70°C	ט י	0.6		
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	137	°C/W		
Total Power Dissipation (Note 7)	T _A = +25°C	PD	2.1	W	
Total Fower Dissipation (Note 1)	T _A = +70°C	ט ז	1.4		
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	$R_{\theta JA}$	59	°C/W	
Thermal Resistance, Junction to Case (Note 7)		R ₀ JC	7.8	°C/W	
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

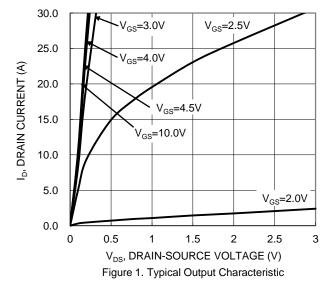
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	V _{DS} = 24V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	1	1.4	2.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		_	4.0	5.5	0	V _{GS} = 10V, I _D = 20A	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	4.9	9	mΩ	$V_{GS} = 4.5V, I_D = 16A$	
Diode Forward Voltage	V_{SD}	_	0.68	1	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)			•	•			
Input Capacitance	C _{iss}	_	2,000	_	pF		
Output Capacitance	Coss	_	315	_	pF	$V_{DS} = 15V, V_{GS} = 0V,$ -f = 1MHz	
Reverse Transfer Capacitance	C _{rss}	_	248	_	pF		
Gate Resistance	Rq	_	2.2	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qq	_	20	_	nC		
Total Gate Charge (V _{GS} = 10V)	Qq	_	42	_	nC	15// 45/	
Gate-Source Charge	Q _{gs}	_	4.7	_	nC	$V_{DS} = 15V, I_{D} = 15A$	
Gate-Drain Charge	Q_{gd}	_	7.4	_	nC		
Turn-On Delay Time	t _{D(ON)}	_	3.9	_	ns		
Turn-On Rise Time	t _R	_	4.1	_	ns	V _{DD} = 15V, V _{GS} = 10V,	
Turn-Off Delay Time	t _{D(OFF)}	_	31	_	ns	$R_G = 3.3\Omega, I_D = 15A$	
Turn-Off Fall Time	t _F	_	14.6	_	ns	1	
Reverse Recovery Time	t _{RR}	_	15	_	ns	154 174 1004	
Reverse Recovery Charge	Q_{RR}	_	6	_	nC	I _F = 15A, di/dt = 100A/µs	

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. Notes:

7. Thermal resistance from junction to soldering point (on the exposed drain pad).

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.





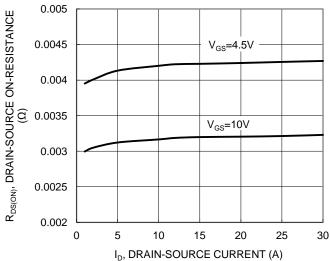


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

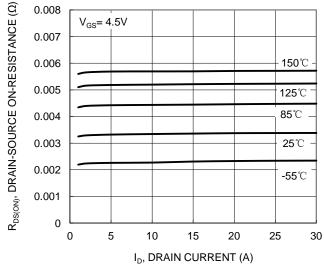


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

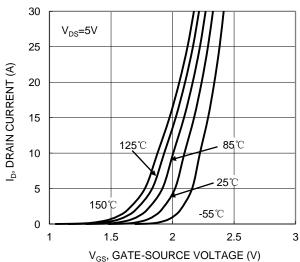


Figure 2. Typical Transfer Characteristic

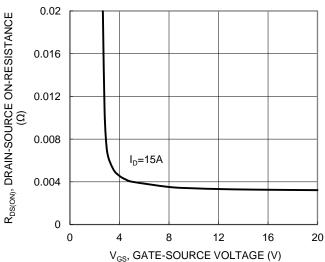


Figure 4. Typical Transfer Characteristic

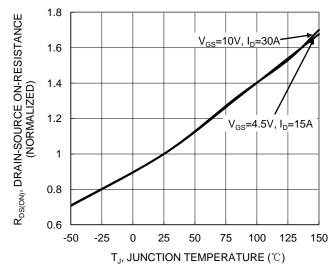


Figure 6. On-Resistance Variation with Temperature





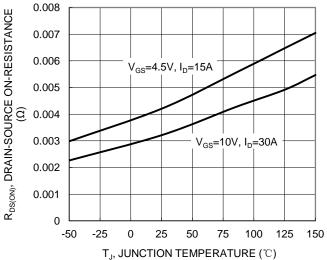
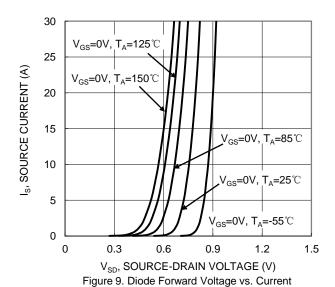


Figure 7. On-Resistance Variation with Temperature



1000 C_{iss} C_{rss} C_{rss} 1000 C_{rss} DRAIN-SOURCE VOLTAGE (V) Figure 11. Typical Junction Capacitance

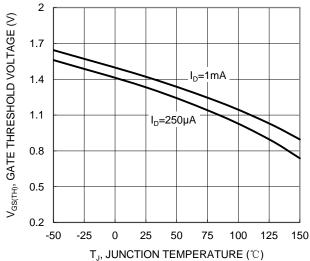
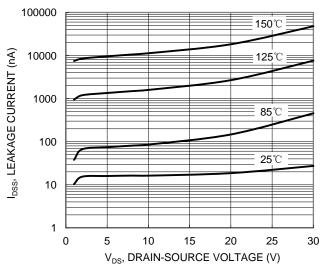


Figure 8. Gate Threshold Variation vs. Junction Temperature



V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 10. Typical Drain-Source Leakage Current vs. Voltage

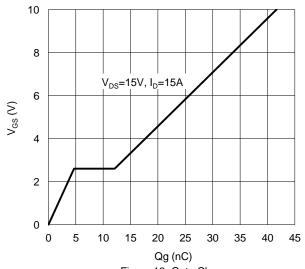


Figure 12. Gate Charge

10000

f=1MHz



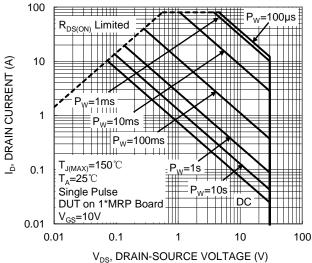


Figure 13. SOA, Safe Operation Area

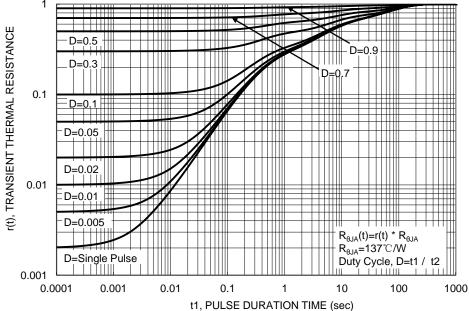


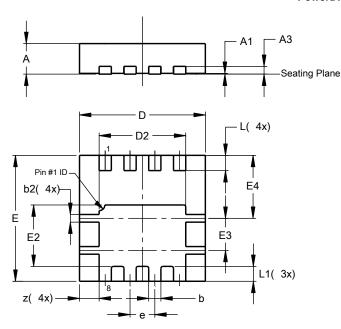
Figure 14. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

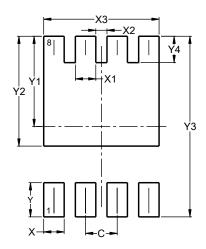


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	_	_	0.203		
b	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е	_	_	0.65		
L	0.35	0.45	0.40		
L1	_	_	0.39		
Z	_	_	0.515		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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